TCAD + AllPix2 pipeline for the ATLAS ITk-Strip Digitization Model

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ITk-Strip Basics

- For HL-LHC, new ATLAS charged-particle tracker (ITk) with inner **Pixel** and outer **Strip** detectors
- ITk-Strip: 4 barrel layers and 6 endcap disks of paired strip sensors



ITk-Strip Basics

- Sensors are AC-coupled **n-type** implants in a **p-type** bulk, separated by **p-stops**
- Expect lifetime fluences of ~50 MRad, or 1.6×10¹⁶ 1-MeV n_{eq}/cm^2
 - Nominally biased to ~300V, increasable to ~700 V to counteract radiation damage



Photo & simulation of sensor strips & edge

Motivation for Precise Digitization Model

Extreme radiation fluences will degrade performance of silicon sensor

- Operational: How to adapt? When & how high should we increase bias voltage?
- MC Simulation: Tracker modeling of charge-collection inefficiency & charge sharing between sensors



Current Digitization Strategy

- For current ATLAS tracker, only Pixel layers simulate performance after radiation damage
 - For HL-LHC, radiation damage of outermost strip detector will be significant & needs simulation
- Simulation propagates groups of deposited charges
 calculates induced readout signal from drift & trapping



Current Digitization Strategy

- Complex simulation utilizes fluence-specific inputs at several points:
 - Electric field
 - Weighting (Ramo) potential
 - Trapping constant
- Slow to run, not tenable in HL-LHC conditions



Modelling radiation damage to pixel sensors in the ATLAS detector

Current Digitization Strategy

- Complex simulation utilizes fluence-specific inputs at several points:
 - **Electric field**
 - Weighting (Ramo) potential •
 - **Trapping constant**
- Slow to run, not tenable in HL-LHC conditions

But gives very accurate predictions!

10¹⁵



Modelling radiation damage to pixel sensors in the ATLAS detector

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Simplified Digitization Strategy

- Complex simulation utilizes fluence-specific inputs at several points:
 - Electric field
 - Weighting (Ramo) potential
 - Trapping constant
- Slow to run, not tenable in HL-LHC conditions

- Exploring simplified method using look-up tables (**LUTs**) to parameterize charge propagation vs deposition depth
 - Simple implementation
 - Faster simulation (~3x speedup for Run 3)
 - Also gives accurate predictions!
- Working with Université Paris Cité (Marco Bomben & Keerthi Nakkalil) who created proof-of-concept for ITk-Pixel
 - See recent talk at Pixel2024 & paper describing method





Modelling radiation damage to pixel sensors in the ATLAS detector

LUT Pipeline

Streamlined simulation infrastructure for ITk-Strip to generate look-up table (**LUT**) models fairly easily in ~1 day



TCAD: Generate detailed sensor field maps with custom ITk-Strip Sensor model



AllPix2: Simulate propagation, scan across charge-deposition positions

Derive LUTs

LUT closure checks



Translate to luminosity estimates (Geant4)

Import into Athena database for use & physics validation

ITk-Strip TCAD model



1()

 TCAD simulation of ITk-Strips being tested with various public models of radiation-induced trapping (see TCAD talk by Yuzhan Zhao) **TCAD**: Generate detailed sensor field maps with custom ITk-Strip Sensor model

• Custom python integrations to greatly increase flexibility for massive parameter scans



Unirradiated Electric Field evolution across 5 strips (log scale)

ITk-Strip TCAD model

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- TCAD simulation of ITk-Strips being tested with various public models of radiation-induced trapping (see TCAD talk by Yuzhan Zhao)
 - Custom python integrations to greatly increase flexibility for massive parameter scans



Density of hole carriers @ 100V

TCAD: Generate detailed sensor field maps with custom ITk-Strip Sensor model

ITk-Strip TCAD model



 TCAD simulation of ITk-Strips being tested with various public models of radiation-induced trapping (see TCAD talk by Yuzhan Zhao) **TCAD**: Generate detailed sensor field maps with custom ITk-Strip Sensor model

- Custom python integrations to greatly increase flexibility: massive parameter scans & automated plotting
- Validate models with QC (unirradiated) & QA (irradiated) test-structure data from ITk-Strip sensor community
 - No existing model is consistently performant across fluences, bias voltages, temperatures
 - <u>Pursuing custom ITk Strip model</u> at Carleton, informed by direct measurements of silicon defects (see DLTS talk by Christoph Klein)



Leakage current data & simulated models, normalized at 250 V

Charge Propagation Simulations

AllPix2: Simulate propagation, scan across charge-deposition positions

- <u>AllPix2 strategy</u> to convert TCAD fields into human-readable AllPix2 format, derive Weighting Potential from ΔElectrostaticPotential
- Simulate charge propagation via AllPix2 TransientPropagator
- Scan across various depths of deposited charge



Charge propagation from center of sensor without / with radiation

Building Look-up Tables



Derive LUTs

LUT closure checks

- Developing unified framework across ITk-Strip & ITk-Pixel for deriving LUTs
 - Fit or interpolate TransientPropagator results vs. charge deposition depth
 - Key distributions are Charge Collection Efficiency & Lorentz Angle
- New LUTPropagator module implemented in AllPix2 utilizes LUTs for fast validation against TransientPropagator



ATLAS Software Integration





Translate to luminosity estimates (Geant4)

Import into Athena database for use & physics validation

- TCAD+AllPix2 pipeline repeated for various fluence estimates (in steps of $\sim 5 \times 10^{14} n_{eq}/cm^2$)
- ATLAS MC generated in "campaigns" to match single year of data
 → different fluences for different layers at a specific integrated luminosity
 - Fluences of each layer estimated from Geant4 / Fluka simulations
 - Predicts < 30% variation across length of barrel layers \rightarrow use average estimate for each layer
 - No endcap implementation yet due to complex geometry & fluence profile
- Strategy allows digitization model re-calculation as data collected without rerunning TCAD+AllPix2

Conclusion

- Exploring custom TCAD models of irradiated ITk-Strip sensors, including DLTS-measured lattice defects
- Automated pipeline builds LUTs from sensor simulations utilizing TCAD & AllPix2
 - Straightforward to run: Template for running TCAD followed by python framework connecting simulations
 - Pre-produce LUT models at various fluences (& voltages) → as HL-LHC progresses translate to luminosity-specific estimates on the fly
- LUTPropagator module & example LUT calculation scripts will be made available via AllPix2

